NSN 5961-01-325-1777

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-1777 **Inclosure Material:** Plastic **Overall Length:** Between 0.160 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches **Function For Which Designed:** Rectifier **End Application:** 4920-01-230-5964 test set, engine operation Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 repetitive peak reverse voltage and 150.0 working peak reverse voltage and 150.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes collector current, dc and 2.00 amperes source cutoff current absolute and 35.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: